

Notice of References Cited		Application/Control No. 09/842,802	Applicant(s)/Patent Under Reexamination NOGUCHI ET AL.
		Examiner Matthew J Song	Art Unit 1765

U.S. PATENT DOCUMENTS

*	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
A	US-5,834,803	11-1998	Nashimoto, Keiichi	257/295
B	US-			
C	US-			
D	US-			
E	US-			
F	US-			
G	US-			
H	US-			
I	US-			
J	US-			
K	US-			
L	US-			
M	US-			

FOREIGN PATENT DOCUMENTS

*	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
N					
O					
P					
Q					
R					
S					
T					

NON-PATENT DOCUMENTS

*	Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages		
U	Park et al. "Fabrication of PbZrxTi1-xO3 Films on Si Structures Using Y2O3 Buffer layers", (1998), Jpn. J. Appl. Phys. Vol. 37 pp 5145-5149.		
V			
W			
X			

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.